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COMPLIANT

HALOGEN

FREE

Hyperfast Rectifier, 2 A FRED Pt®



SlimSMAW (DO-221AD)

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 A				
V_R	100 V, 200 V				
V _F at I _F	0.69 V				
I _{FSM}	60 A				
t _{rr} (typ.)	15 ns				
T _J max.	175 °C				
Package	SlimSMAW (DO-221AD)				
Circuit configuration	Single				

FEATURES

- Low profile package
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Class 2 whisker test
- Compatible to SOD-128 package case outline
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

For use in high frequency, freewheeling, DC/DC converters, PFC, and in snubber industrial, and automotive applications.

MECHANICAL DATA

Case: SlimSMAW (DO-221AD)

Molding compound meets UL 94 V-0 flammability rating

Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per

J-STD-002

Polarity: color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse	VS-2EYH01-M3	W		100	V	
voltage	VS-2EYH02-M3	V_{RRM}		200	V	
Average rectified forward current		I _{F(AV)} (1)	T _C = 151 °C	2	Α	
Non-repetitive peak surge current		I _{FSM}	T _J = 25 °C, 10 ms sine pulse wave	60		
Operating junction and storage temperatures		T _J , T _{Stg}		-55 to +175	°C	

Note

(1) Mounted on infinite heatsink

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking VS-2EYH01-M3	- V _{BR} , V _R	Ι _R = 100 μΑ	100	-	-	- V
voltage VS-2EYH02-M3			200	-	-	
Forward voltage, per diode	W	I _F = 2 A	-	0.86	0.93	
Forward voitage, per diode	V _F	I _F = 2 A, T _J = 150 °C	=	0.69	0.75	
Reverse leakage current, per diode		V _R = V _R rated	-	-	2	μΑ
neverse leakage current, per diode	I _R	$T_J = 150 ^{\circ}\text{C}, V_R = V_R \text{rated}$	-	-	20	
Junction capacitance	C _T	V _R = 200 V	-	12	-	pF

Revision: 28-Jan-2021 **1** Document Number: 96514 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u>

VS-2EYH01-M3, VS-2EYH02-M3

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t _{rr}	$I_F = 1.0 \text{ A}, dI_F/dt =$	$I_F = 1.0 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		22	-	
		$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		ı	15	-	ns
		$I_F = 0.5 \text{ A}, I_R = 1 \text{A}, I_{rr} = 0.25 \text{ A}$		-	-	28	
		T _J = 25 °C	I _F = 2 A, dI _F /dt = 200 A/μs, V _R = 100 V	-	16	-	
		T _J = 125 °C		1	26	-	
Peak recovery current	I _{RRM}	T _J = 25 °C		-	2.7	-	Α
		T _J = 125 °C		-	3.4	-	_ ^
Reverse recovery charge	Q.,,	T _J = 25 °C		-	20	-	nC
		T _J = 125 °C		-	43	-	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range		T _J , T _{Stg}		-55	-	175	°C	
Thermal resistance, junction to mount		R _{thJM} ⁽¹⁾	Infinite heatsink	-	12	15		
Thermal resistance, junction to ambient		R _{thJA}	Device mounted on FR4 PCB, 2 oz. standard footprint	-	120	150	°C/W	
VS-2EYH01-M3			Coop at the Clim CMANN (DO 201AD)	2H1				
Marking device	VS-2EYH02-M3		Case style SlimSMAW (DO-221AD)		2H2			

Note

⁽¹⁾ Thermal resistance junction to mount follows JEDEC® 51-14 transient dual interface test method (TDIM)

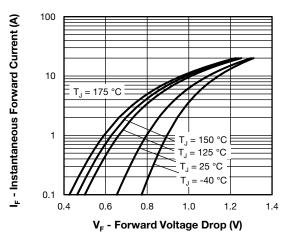


Fig. 1 - Typical Forward Voltage Drop Characteristics

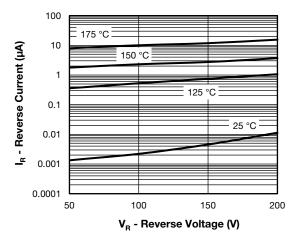


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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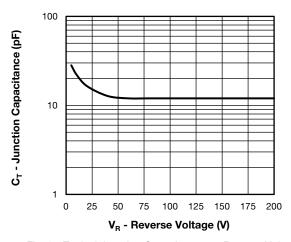


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

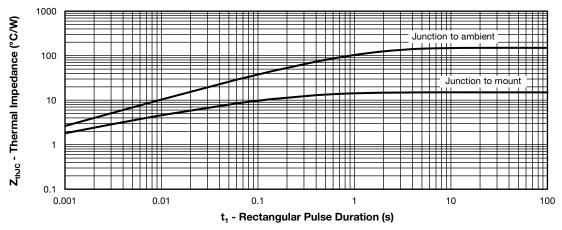


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

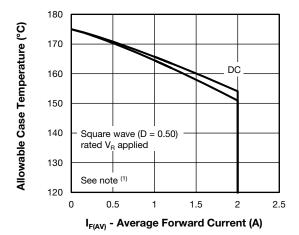


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

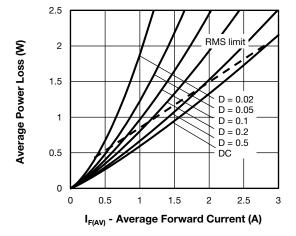


Fig. 6 - Forward Power Loss Characteristics

Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (\text{Pd} + \text{Pd}_{\text{REV}}) \times R_{\text{thJC}}; \\ \text{Pd} = & \text{forward power loss} = I_{\text{F(AV)}} \times V_{\text{FM}} \text{ at } (I_{\text{F(AV)}}/D) \text{ (see fig. 5)}; \\ \text{Pd}_{\text{REV}} = & \text{inverse power loss} = V_{\text{R1}} \times I_{\text{R}} \text{ (1 - D)}; I_{\text{R}} \text{ at } V_{\text{R1}} = \text{rated } V_{\text{R}} \\ \end{array}$

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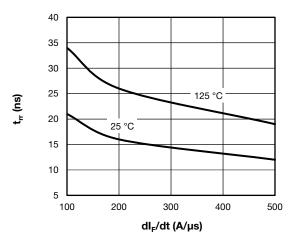


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

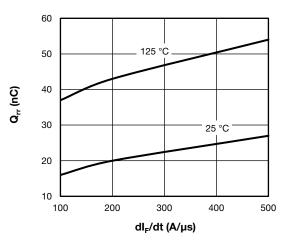
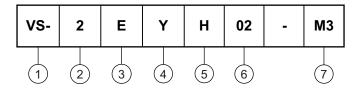


Fig. 8 - Typical Stored Charge vs. dl_F/dt

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (2 = 2 A)

3 - Circuit configuration:

E = single diode

4 - Y = SlimSMAW (DO-221AD)

5 - Process type,

H = hyperfast recovery

6 - Voltage code (02 = 200 V)

7 - M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	PACKAGING DESCRIPTION			
VS-2EYH01-M3/H	0.033	Н	3500	7"diameter plastic tape and reel			
VS-2EYH01-M3/I	0.033	I	14 000	13"diameter plastic tape and reel			
VS-2EYH02-M3/H	0.033	Н	3500	7"diameter plastic tape and reel			
VS-2EYH02-M3/I	0.033	I	14 000	13"diameter plastic tape and reel			

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?96582</u>					
Part marking information	www.vishay.com/doc?95562				
Packaging information	www.vishay.com/doc?88869				
SPICE model	www.vishay.com/doc?96585				

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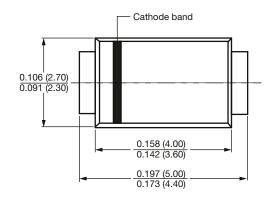


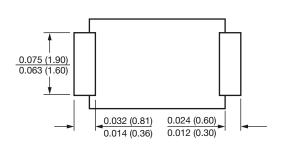
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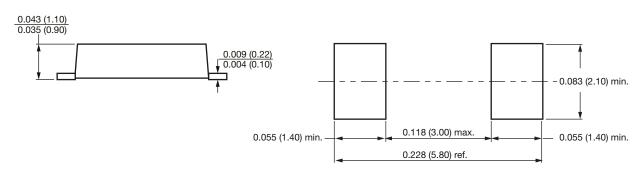
SlimSMAW (DO-221AD)

DIMENSIONS in inches (millimeters)

SlimSMAW (DO-221AD)







Mounting pad layout

Legal Disclaimer Notice



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